

HiPerFAST™ IGBT

IXGH 24N60A

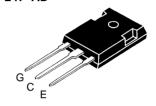
 V_{CES} = 600 V I_{C25} = 48 A $V_{CE(sat)}$ = 2.7 V t_{fi} = 275 ns



Symbol	Test Conditions	Maximum	Maximum Ratings		
V _{ces}	$T_{\downarrow} = 25^{\circ}\text{C to } 150^{\circ}\text{C}$	600	V		
$\mathbf{V}_{\mathtt{CGR}}$	$T_{_J} = 25^{\circ}C$ to $150^{\circ}C$; $R_{_{GE}} = 1 \text{ M}\Omega$	600	V		
V _{GES}	Continuous	±20	V		
$V_{\scriptscriptstyle{GEM}}$	Transient	±30	V		
I _{C25}	T _c = 25°C	48	А		
I _{C90}	$T_{\rm C} = 90^{\circ} C$	24	Α		
I _{CM}	$T_{\rm C}$ = 25°C, 1 ms	96	Α		
SSOA (RBSOA)	V_{GE} = 15 V, T_{VJ} = 125°C, R_{G} = 22 Ω Clamped inductive load, L = 100 μ H	I _{CM} = 48 @ 0.8 V _{CES}	Α		
P _c	T _c = 25°C	150	W		
T _J		-55 +150	°C		
T _{JM}		150	°C		
T _{stg}		-55 + 150	°C		
M _d	Mounting torque (M3)	1.13/10	Nm/lb.in.		
Weight		6	g		
	ad temperature for soldering 62 in.) from case for 10 s	300	°C		

- 5				-	3
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		J	3	00	°C
Symbol	Test Conditions	Characteristic Values (T _J = 25°C, unless otherwise specified) min. typ. max.			
BV _{CES}	$I_{C} = 250 \mu A, V_{GE} = 0 V$	600			V
$V_{_{GE(th)}}$	I_{C} = 250 μ A, V_{CE} = V_{GE}	2.5		5	V
I _{CES}	V _{CE} = 0.8 • V _{CES} V _{GE} = 0 V	T _J = 25°C T _J = 125°C		200 1	μA mA
I _{GES}	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$			±100	nA

TO-247 AD



G = Gate, C = Collector, E = Emitter, TAB = Collector

Features

- International standard package JEDEC TO-247 AD
- High frequency IGBT
- 2nd generation HDMOS[™] process
- · High current handling capability
- MOS Gate turn-on
 - drive simplicity

Applications

- · AC motor speed control
- · DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

Advantages

2.7

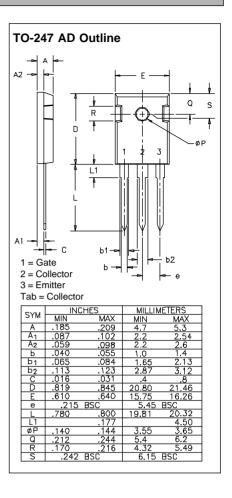
- Easy to mount with 1 screw (isolated mounting screw hole)
- Switching speed for high frequency applications
- · High power density

 $\mathbf{V}_{\mathsf{CE}(\mathsf{sat})}$

 $I_{C} = I_{C90}, V_{GE} = 15 \text{ V}$



Symbol	Test Conditions Characteristics $(T_J = 25^{\circ}C, \text{ unless } c \text{ min.})$	therwis	stic Values se specified) max.
g _{fs}	$I_{\rm C} = I_{\rm C90}; \ V_{\rm CE} = 10 \ V,$ Pulse test, t \leq 300 μ s, duty cycle \leq 2 %	13	S
C _{ies}		1500	pF
\mathbf{C}_{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	135	pF
\mathbf{C}_{res}	}	40	pF
$\overline{\mathbf{Q}_{g}}$)	90	120 nC
\mathbf{Q}_{ge}	$I_{\rm C} = I_{\rm C90}, V_{\rm GE} = 15 \text{ V}, V_{\rm CE} = 0.5 \text{ V}_{\rm CES}$	11	15 nC
\mathbf{Q}_{gc}	}	30	40 nC
t _{d(on)}	Inductive load, T ₁ = 25°C	25	ns
t _{ri}		15	ns
E _{on}	$ \begin{cases} I_{C} = I_{C90}, V_{GE} = 15 \text{ V, L} = 100 \mu\text{H,} \\ V_{CE} = 0.8 V_{CES}, R_{G} = R_{off} = 10 \Omega \end{cases} $	0.6	mJ
$\mathbf{t}_{d(off)}$	Remarks: Switching times may increase	150	200 ns
t _{fi}	for V_{CE} (Clamp) > 0.8 • V_{CES} , higher T_J or	110	270 ns
E_{off}	increased R _G	1.5	mJ
t _{d(on)}	Inductive load, T ₁ = 125°C	25	ns
t _{ri}	$I_{C} = I_{C90}, V_{GF} = 15 \text{ V}, L = 100 \mu\text{H}$	15	ns
E _{on}	$V_{CE} = 0.8 V_{CES}, R_{G} = R_{off} = 10 \Omega$	0.8	mJ
$\mathbf{t}_{d(off)}$	Remarks: Switching times may increase	250	ns
t _{fi}	for V_{CE} (Clamp) > 0.8 • V_{CES} , higher T_1 or	400	ns
E_{off}) increased R _g	2.3	mJ
R _{thJC}			0.83 K/W
R_{thCK}		0.25	K/W



IXGH 24N60A characteristic curves are located on the IXGH 24N60AU1 data sheet.